TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC5562

Switching Regulator and High-Voltage Switching Applications

DC-DC Converter Applications

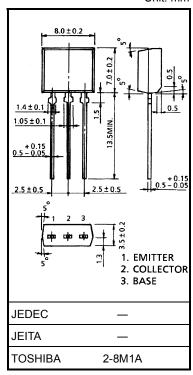
• Excellent switching times: $t_r = 0.7 \ \mu s \ (max)$

$$t_f = 0.5 \ \mu s \ (max), \ (I_c = 0.3 \ A)$$

- High breakdown voltage: $V_{CEO} = 800 \text{ V}$
- High-speed DC-DC converter applications

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	900	V	
Collector-emitter voltage		V _{CEO}	800	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	Ι _C	0.8	A	
	Pulse	I _{CP}	1.5		
Base current		Ι _Β	0.4	А	
Collector power dissipation		P _C	1.3	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.55 g (typ.)

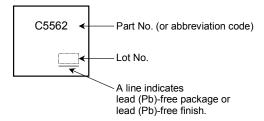
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current		I _{CBO}	V _{CB} = 720 V, I _E = 0		_	100	μA	
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0	-	_	1	mA	
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _E = 0	900	_	_	V	
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	800	_	_	V	
DC current gain		h _{FE(1)}	V _{CE} = 5 V, I _C = 1 mA	10	_	_	_	
		h _{FE(2)}	V _{CE} = 5 V, I _C = 0.08 A	15	_	60		
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 0.3 A, I _B = 0.06 A		_	1.0	V	
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.3 A, I _B = 0.06 A	-	_	1.2	V	
Switching time Stor	Rise time	tr	$20 \ \mu s$ $Input$ $IB1$ $IB1$ $IB2$ $V_{CC} \approx 360 \ V$ $I_{B1} = 0.06 \ A, \ I_{B2} = -0.12 \ A,$ Duty cycle $\leq 1\%$	_	_	0.7	μs	
	Storage time	t _{stg}		_	_	4.5		
	Fall time	t _f		_	_	0.5		

Unit: mm

TOSHIBA

Marking



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